NSN 5961-01-482-0915

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-482-0915 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.146 inches **Terminal Length:** Between 0.016 inches and 0.022 inches **End Application:** Fighter aircraft-first (f18 e/f); first pbl **Mounting Method:** Press fit **Terminal Circle Diameter:** Between 0.063 inches and 0.067 inches **Criticality Code Justification:** Agav **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.0 forward voltage, dc **Current Rating Per Characteristic:** 0.01 microamperes collector current, dc peak **Product Name:** Inavy: diode, zener, aircraft **Special Features:** Modified; unleaded/surface mounted; metallurgical bond **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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